2SD2138A

Silicon NPN triple diffusion planar type darlington

For power amplification Complementary to 2SB1418A

■ Features

- High forward current transfer ratio h_{FE} which has satisfactory linearity.
- Allowing supply with the radial taping

■ Absolute Maximum Ratings $T_C = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	80	V	
Collector-emitter voltage (Base open)	V _{CEO}	V _{CEO} 80		
Emitter-base voltage (Collector open)	V _{EBO}	5	V	
Collector current	I_{C}	2	A	
Peak collector current	I_{CP}	4	A	
Collector power dissipation	D	15	W	
$T_C = 25^{\circ}C$	$P_{\rm C}$	2.0		
Junction temperature	T_j	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	

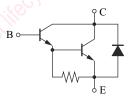
■ Package

• Code

MT-4-A1

- Pin Name
 - 1. Base
 - 2. Collector
 - 3. Emitter

■ Internal Connection



■ Electrical Characteristics $T_C = 25$ °C±3°C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_C = 30 \text{ mA}, I_B = 0$	80			V
Base-emitter voltage	$V_{ m BE}$	$V_{CE} = 4 \text{ V}, I_C = 2 \text{ A}$			2.8	V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 80 \text{ V}, I_{E} = 0$	60,		100	μΑ
Collector-emitter cutoff current (Base open)	I_{CEO}	$V_{CE} = 40 \text{ V}, I_{B} = 0$			100	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 5 \text{ V}, I_{C} = 0$			100	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = 4 \text{ V}, I_{C} = 1 \text{ A}$	1 000			
	h _{FE2} *	$V_{CE} = 4 \text{ V}, I_C = 2 \text{ A}$	2000		10000	
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = 2 A, I_B = 8 mA$			2.5	V
Transition frequency	f_T	$V_{CE} = 10 \text{ V}, I_{C} = 0.5 \text{ A}, f = 1 \text{ MHz}$		20		MHz
Turn-on time	t _{on}	$I_C = 2 \text{ A}, I_{B1} = 8 \text{ mA}, I_{B2} = -8 \text{ mA},$		0.4		μs
Turn-off time	$t_{\rm off}$	$V_{CC} = 50 \text{ V}$		4		μs

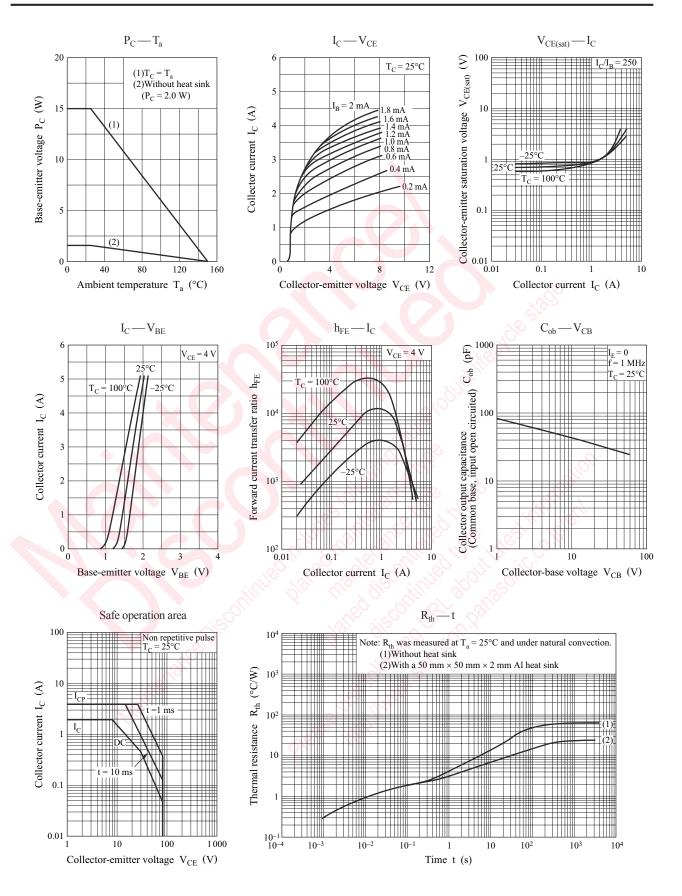
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: Rank classification

Rank	Q	Р
h_{FE2}	2000 to 5000	4000 to 10000

2SD2138A

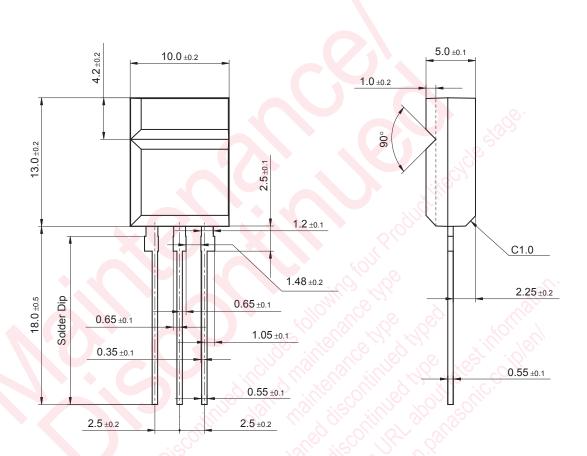
Panasonic

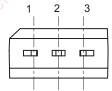


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Panasonic 2SD2138A

MT-4-A1 Unit: mm





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